



MBR16xx, MBRF16xx & MBRB16xx Series

Schottky Barrier Rectifiers
Reverse Voltage 35 to 60 Volts Forward Current 16.0 Amperes

Features

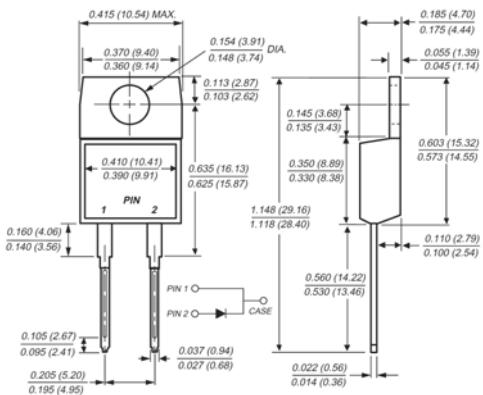
- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Guardring for overvoltage protection
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.25" (6.35mm) from case



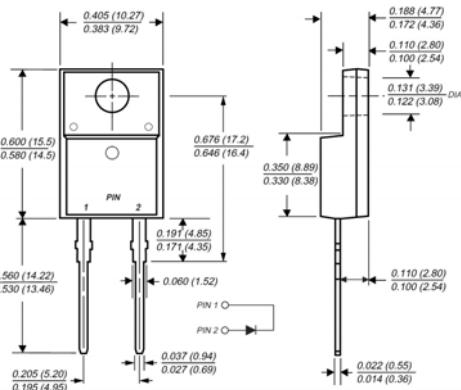
Mechanical Data

- ◆ Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded plastic body
- ◆ Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- ◆ Polarity: As marked
- ◆ Mounting Position: Any
- ◆ Mounting Torque: 10 in-lbs maximum
- ◆ Weight: 0.08 ounce, 2.24 grams

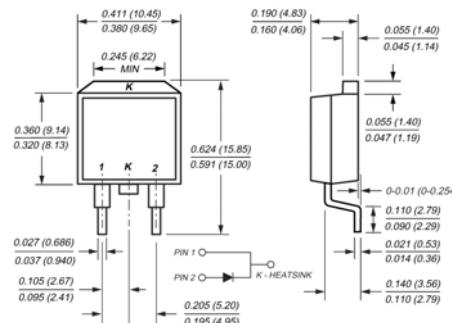
TO-220AC



ITO-220AC

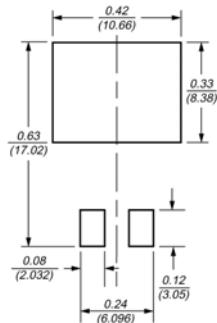


TO-263AB(D²PAK)



Dimensions in inches and (millimeters)

Mounting Pad Layout TO-263AB



Maximum Ratings and Electrical Characteristics

($T_c = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	MBR1635	MBR1645	MBR1650	MBR1660	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	Volts
Working peak reverse voltage	V_{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V_{DC}	35	45	50	60	Volts
Maximum average forward rectified current at $T_c=125^\circ\text{C}$	$I_{F(AV)}$			16		Amps
Peak repetitive forward current (rated V_F , sq. wave, 20KHz) at $T_c=125^\circ\text{C}$	I_{FRM}			32		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}			150		Amps
Peak repetitive reverse current at $t_p = 2.0\mu\text{s}$, 1KHz	I_{RRM}		1.0		0.5	Amps
Voltage rate of change (rated V_F)	dv/dt		10,000		1,000	V/ μs
Maximum instantaneous forward voltage (Note 4) at $I_F=16\text{A}$, $T_c=25^\circ\text{C}$ at $I_F=16\text{A}$, $T_c=125^\circ\text{C}$	V_F		0.63 0.57		0.75 0.65	Volt
Maximum instantaneous reverse current at rated DC blocking voltage (Note 4) $T_c=25^\circ\text{C}$ $T_c=125^\circ\text{C}$	I_R		0.2 40		1.0 50	mA
Typical thermal resistance from junction to case	R_{TJC}			MBR 1.5 / MBRF 3.0 / MBRB 1.5		°C/W
RMS Isolation voltage (MBRF type only) from terminals to heatsink with $t = 1.0$ second, RH $\leq 30\%$	V_{ISOL}			4500 (Note 1) 3500 (Note 2) 1500 (Note 3)		Volts
Operating junction temperature range	T_J			-55 to +150		°C
Storage temperature range	T_{STG}			-55 to +150		°C

Notes: 1. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset

2. Clip mounting (on case), where leads do overlap heatsink

3. Screw mounting with 4-40 screw, where washer diameter is < 4.9 mm (0.19")

4. Pulse test: 300μs pulse width, 1% duty cycle

RATINGS AND CHARACTERISTIC CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

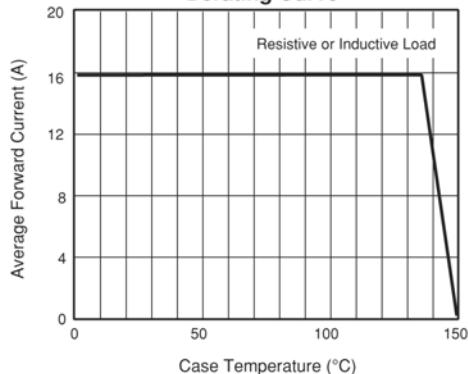


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

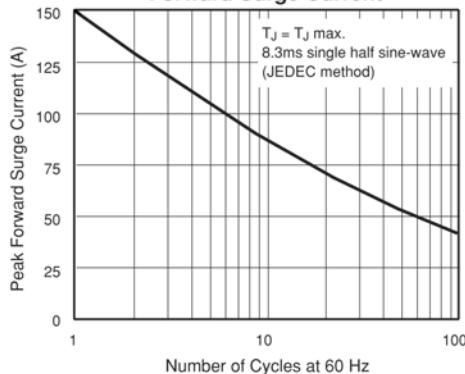


Fig. 3 - Typical Instantaneous Forward Characteristics

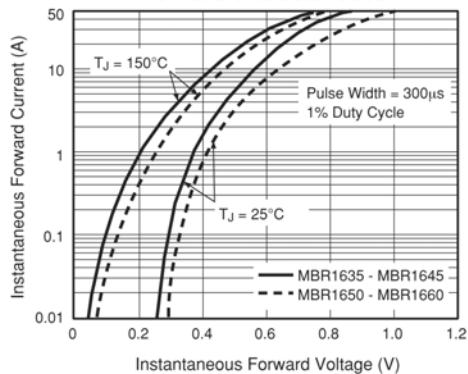


Fig. 4 - Typical Reverse Characteristics

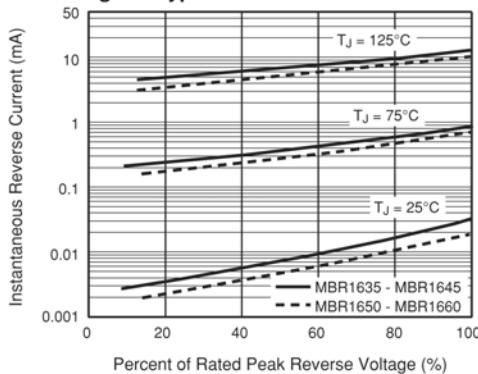


Fig. 5 - Typical Junction Capacitance

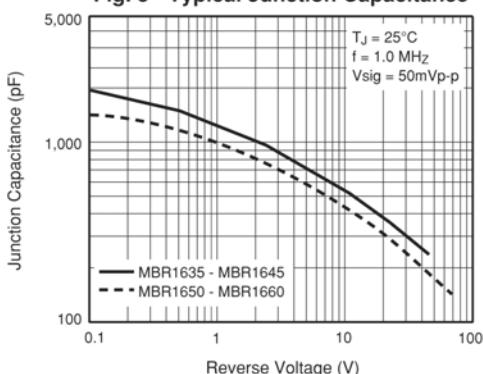


Fig. 6 - Typical Transient Thermal Impedance

